





MBR230LS SURFACE MOUNT SCHOTTKY BARRIER DIODE



Features

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

• Case: SOD-123, Molded Plastic

Terminals: Plated Leads Solderable per MIL-STD-202,

Method 208

Polarity: Cathode Band

Maximum Ratings @T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	30	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle, rectangular wave form	2	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	25	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	\/	@ 0.5A, Pulse, T _J = 25 °C	0.28	0.30	\/
	V _{F1}	@ 2A, Pulse, T _J = 25 °C	0.42	0.50	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.4	1	mA
Junction Capacitance	C _j	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	71	100	pF
Voltage Rate of Change	dv/dt	-	-	10000	V/μs

^{*} Pulse width < 300 μs, duty cycle < 2%

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



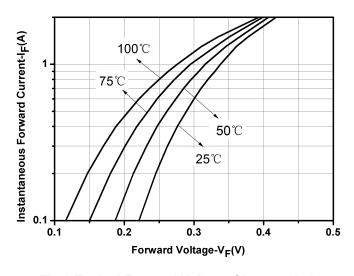




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +100	°C
Storage Temperature	T _{stg}	-	-55 to +100	°C
Typical Thermal Resistance, Junction to Ambient	R _{0JA}	-	244	°C/W
Approximate Weight	wt	-	0.028	g
Case Style	SOD-123			

Ratings and Characteristics Curves



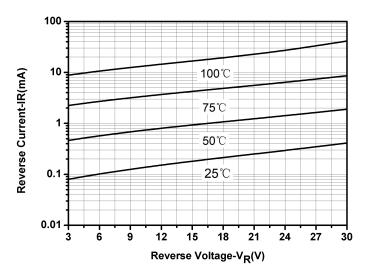


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics

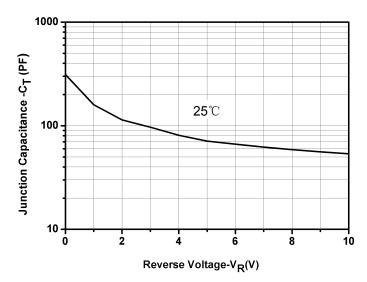


Fig.3-Capacitance vs. Reverse Voltage

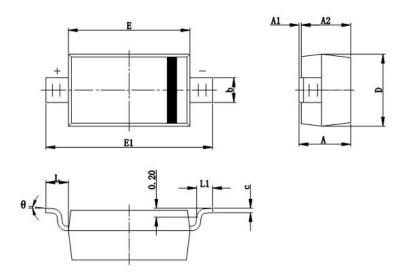
- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Mechanical Dimensions SOD-123



OVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.450	0.650	0.018	0.026	
С	0.080	0.150	0.003	0.006	
D	1.500	1.700	0.059	0.067	
Е	2.600	2.800	0.102	0.110	
E1	3.550	3.850	0.140	0.152	
L	0.500 REF.		0.020	REF.	
L1	0.250	0.450	0.010	0.018	
θ	0°	8°	0°	8°	

Ordering Information

Device	Package	Shipping
MBR230LS	SOD-123	2000noo / rool
IVIDRZSULS	(Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

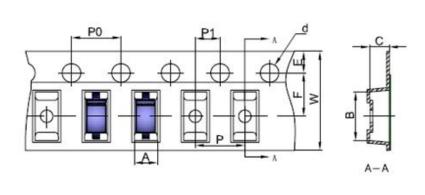


Where X is Date Code

B3N = Part Name

MBR230LS

Carrier Tape Specification SOD-123



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	1.80	1.90	
В	3.89	3.99	
С	1.52	1.62	
d	1.45	1.65	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..